

LT1□□82A Series

Dichromatic Chip LED
Devices With Inner Lens

■ Model No.

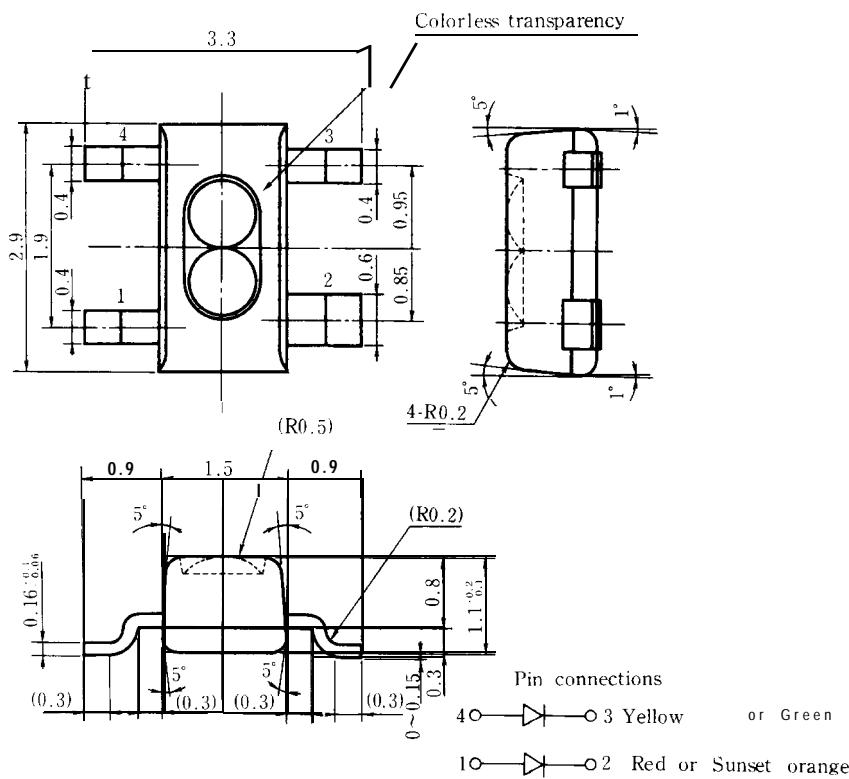
LT1EL82A	Yellow-green	GaP
	Red (High-luminosity)	GaAlAs/GaAs
LT1ET82A	Yellow-green	GaP
	Red (High-luminosity)	GaAlAs/GaAs
LT1KS82A	Green	GaP
	Sunset orange	GaAsP/GaP

■ Features

1. Inner-lens type
2. Radiation size 1.5×2.9mm
3. Colorless transparency lens type
4. Taped models : Tape width 8mm, 3,000 pcs/reel

■ Outline Dimensions

(Unit: mm)



Unspecified tolerance: ±0.2mrr

Regarding the taping specifications, please see "Taped Models" of Appendix

SHARP

LT1□□82A

■ Absolute Maximum Ratings

(Ta=25°C)

Parameter	Symbol	LT1EL82A		LT1ET82A		Unit		
		Yellow-green	Red	Yellow-green	Red			
*1 Power dissipation	P	50	110	50	66	mW		
Continuous forward current	IF	20	50	20	30	mA		
*2 Peak forward current	IFM	50	200	50	50	mA		
Derating factor	DC	—	0.27	0.67	0.27	0.40		
	Pulse	—	0.67	2.67	0.67	0.67		
Reverse voltage	VR	5		5		V		
Operating temperature	Topr	-25 to +85				°C		
Storage temperature	Tsg	-25 to +100				°C		

3

(Ta=25°C)

Parameter	Symbol	LT1KS82A				Unit		
		Green	Sunset orange					
*1 Power dissipation	P	50	84			mW		
Continuous forward current	IF	20	30			mA		
*2 Peak forward current	IFM	50	50			mA		
Derating factor	DC	—	0.27	0.40		m A/°C		
	Pulse	—	0.67	0.67		m A/°C		
Reverse voltage	VR	5				V		
Operating temperature	Topr	-25 to +85				°C		
Storage temperature	Tsg	-25 to +100				°C		

*1 The value of power dissipation is specified under the condition that either yellow-green or red/green or sunset orange is lightened separately. When the both diodes of yellow-green and red/green and sunset orange are lightened simultaneously, the power dissipation of each diode should be less than the half of the value specified in this table.

*2 Duty ratio = 1/10, Pulse width = 0.1ms

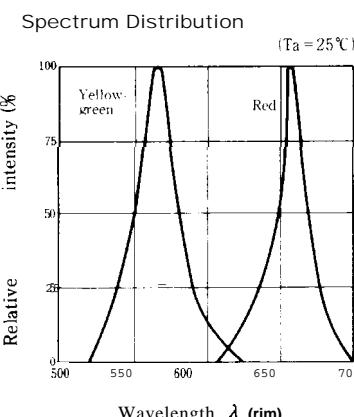
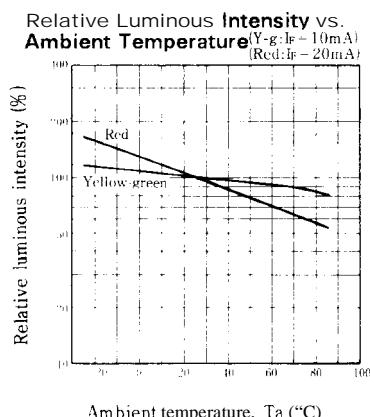
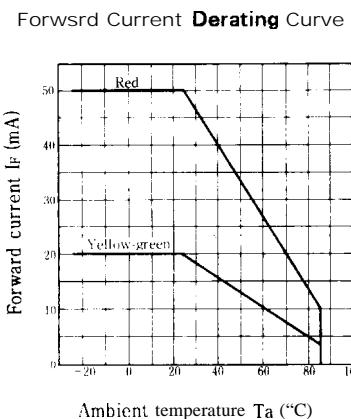
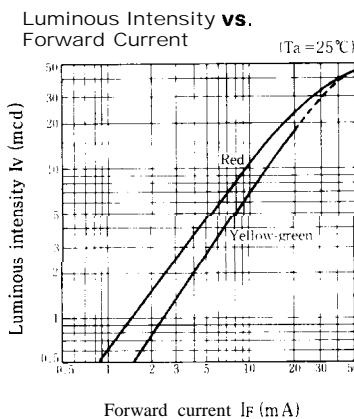
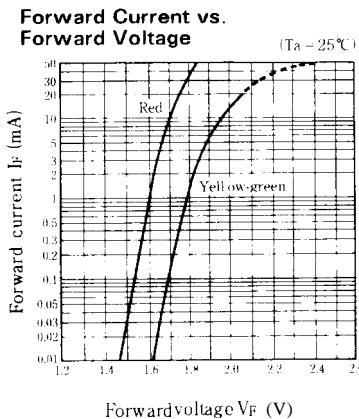
LT1 EL82A (Yellow-green/Red)

■ Electro-optical Characteristics

Parameter	Symbol	Radiation color	Conditions	MIN.	TYP.	MAX.	Unit
Forward voltage	V_F	Yellow-green	$I_F = 10\text{mA}$	—	1.95	2.5	V
		Red	$I_F = 20\text{mA}$	—	1.75	2.2	
*3 Luminous intensity	I_V	Yellow-green	$I_F = 10\text{mA}$	2.7	7.0	—	mcd
		Red	$I_F = 20\text{mA}$	8.2	21.8	—	
Peak emission wavelength	λ_p	Yellow-green	$I_F = 10\text{mA}$	—	565	—	nm
		Red	$I_F = 20\text{mA}$	—	660	—	
Spectrum radiation bandwidth	$\Delta\lambda$	Yellow-green	$I_F = 10\text{mA}$	—	30	—	'm
		Red	$I_F = 20\text{mA}$	—	20	—	
Reverse current	I_R	Yellow-green	$V_o = 4\text{V}$	—	—	10	μA
		Red	$V_R = 4\text{V}$	—	—	10	
Terminal capacitance	C_t	Yellow-green	$V_o = 0\text{V} f = 1\text{MHz}$	—	35	—	*F
		Red	$V_o = 0\text{V} f = 1\text{MHz}$	—	30	—	
Response frequency	f_c	Yellow-green	—	—	4	—	MHz
		Red	—	—	8	—	

*3 Tolerance: $\pm 30\%$

Characteristics Diagrams



LT1 ET82A (Yellow-green/Red)

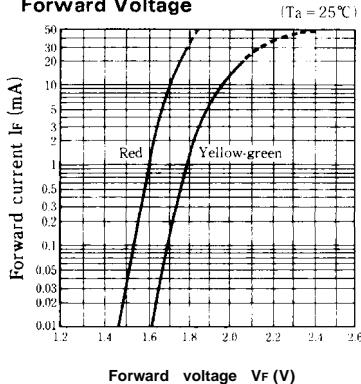
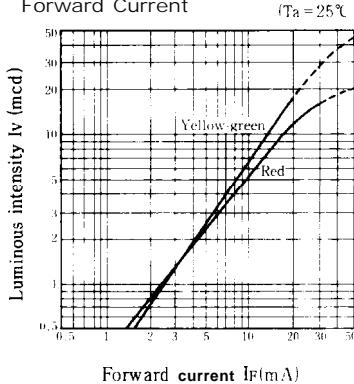
■ Electro-optical Characteristics

(Ta = 25°C)

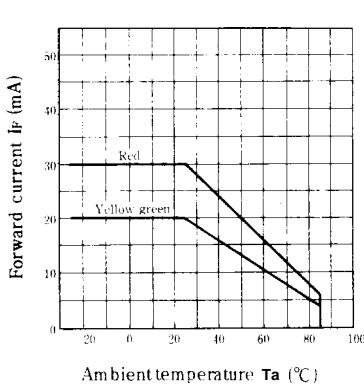
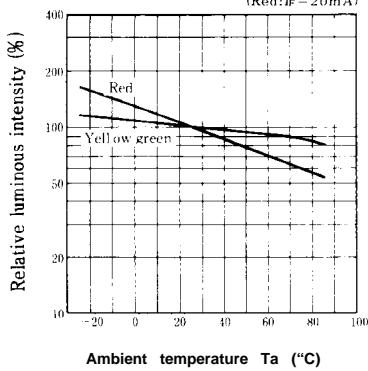
Parameter	Symbol	Radiation color	Conditions	MIN.	TYP.	MAX.	Unit
Forward voltage	V _F	Yellow-green	I _F = 10 mA		1.95	2.5	V
		Red	I _F = 20 mA		1.75	2.2	
※3 Luminous intensity	I _V	Yellow-green	I _F = 10 mA	2.7	7.0	—	mcd
		Red	I _F = 20 mA	4.8	11.8	—	
Peak emission wavelength	λ_p	Yellow-green	I _F = 10 mA	—	565	—	'm
		Red	I _F = 20 mA		660	—	
Spectrum radiation bandwidth	$\Delta\lambda$	Yellow-green	I _F = 10 mA	—	30	—	'm
		Red	I _F = 20 mA		20	—	
Reverse current	I _R	Yellow-green	V _R = 4 V		10	—	μA
		Red	V _R = 4 V	—	—	10	
Terminal capacitance	C _t	Yellow-green	V = 0 V f = 1 MHz	—	35	—	pF
		Red	V = 0 V f = 1 MHz	—	30	—	
Response frequency	f _c	Yellow-green	—	—	4	—	'Hz
		Red	—		8	—	

※3 Tolerance: ±30%

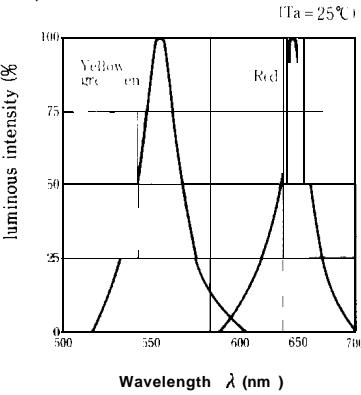
■ Characteristics Diagrams

Forward Current vs.
Forward VoltageLuminous Intensity vs.
Forward Current

Forward Current Derating Curve

Relative Luminous Intensity vs.
Ambient Temperature (Y.g.: I_F = 10 mA)
(Red: I_F = 20 mA)

Spectrum Distribution



SHARP

LT1 KS82A (Green/Sunset orange)

■ Electro-optical Characteristics

(Ta=25°C)

Parameter	Symbol	Radiation color	Conditions	MIN.	TYP.	MAX.	Unit
Forward voltage	V _F	Green	I _F =10mA	—	1.95	2.5	V
		Sunset orange	I _F =20mA	—	2.0	2.8	
*3 Luminous intensity	I _V	Green	I _F =10mA	0.8	2.4	—	mcd
		Sunset orange	I _F =20mA	—	4.0	10.5	
Peak emission wavelength	λ_p	Green	I _F =10mA	—	555	—	nm
		Sunset orange	I _F =20mA	—	610	—	
Spectrum radiation bandwidth	$\Delta\lambda$	Green	I _F =10mA	—	25	—	nm
		Sunset orange	I _F =20mA	—	35	—	
Reverse current	I _R	Green	V _R =4V	—	—	10	μA
		Sunset orange	V _R =4V	—	—	10	
Terminal capacitance	C _t	Green	V=0V f=1MHz	—	40	—	pF
		Sunset orange	V=0V f=1MHz	—	15	—	
Response frequency	f _c	Green	—	—	4	—	Hz
		Sunset orange	—	—	4	—	

*3 Tolerance: ±30%

■ Characteristics Diagrams

